



UD4614

Power MOSFET

DUAL ENHANCEMENT MODE (N-CHANNEL/P-CHANNEL)

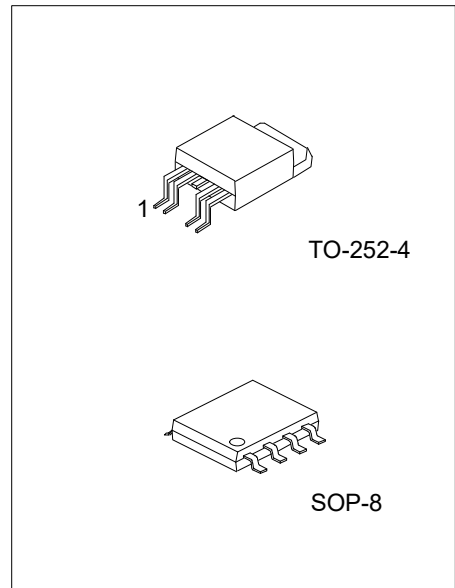
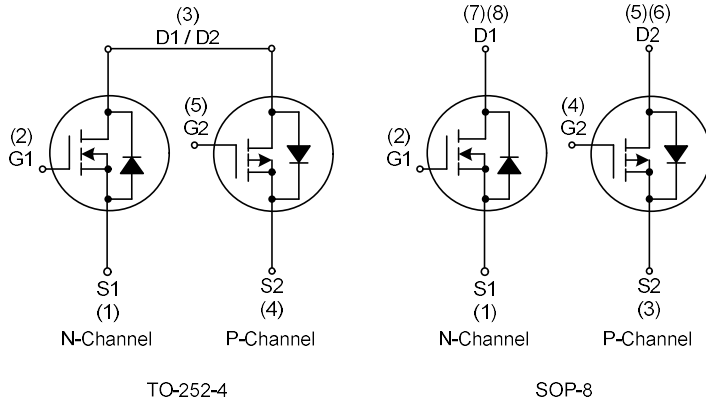
DESCRIPTION

The UTC **UD4614** can provide excellent $R_{DS(ON)}$ and low gate charge by using advanced trench technology MOSFETs. The UTC **UD4614** may be used in H-bridge, inverters and other applications.

FEATURES

- * N-Channel: 40V/6.1A
 $R_{DS(ON)} \leq 31 \text{ m}\Omega$ @ $V_{GS} = 10\text{V}$, $I_D = 6.0\text{A}$
 $R_{DS(ON)} \leq 45 \text{ m}\Omega$ @ $V_{GS} = 4.5\text{V}$, $I_D = 5.0\text{A}$
- * P-Channel: -40V/-5.2A
 $R_{DS(ON)} \leq 45 \text{ m}\Omega$ @ $V_{GS} = -10\text{V}$, $I_D = -5.0\text{A}$
 $R_{DS(ON)} \leq 63 \text{ m}\Omega$ @ $V_{GS} = -4.5\text{V}$, $I_D = -2.0\text{A}$
- * Super high dense cell design
- * Reliable and Rugged

SYMBOL

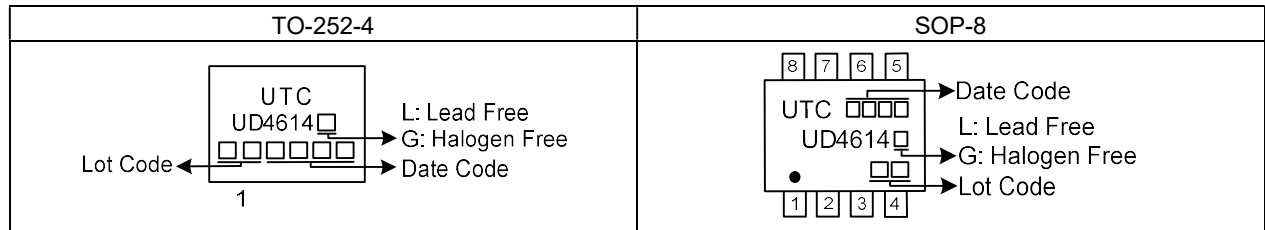


ORDERING INFORMATION

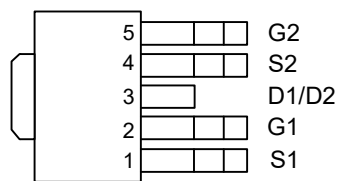
Ordering Number		Package	Packing
Lead Free	Halogen Free		
UD4614L-TN4-R	UD4614G-TN4-R	TO-252-4	Tape Reel
UD4614L-S08-R	UD4614G-S08-R	SOP-8	Tape Reel

<p>UD4614G-TN4-R</p> <ul style="list-style-type: none"> (1) Packing Type (2) Package Type (3) Green Package 	<ul style="list-style-type: none"> (1) R: Tape Reel (2) TN4: TO-252-4, S08: SOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free
--	--

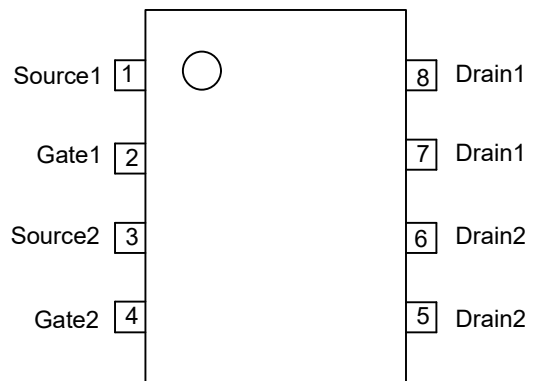
■ **MARKING**



■ **PIN CONFIGURATION**



TO-252-4



SOP-8

■ **ABSOLUTE MAXIMUM RATINGS** ($T_A = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS		UNIT
			N-Channel	P-Channel	
Drain-Source Voltage		V_{DS}	40	-40	V
Gate-Source Voltage		V_{GS}	± 20		V
Continuous Drain Current (Note3)	Continuous	I_D	6.1	-5.2	A
Pulsed Drain Current (Note3)	Pulsed	I_{DM}	24	-24	A
Power Dissipation	$T_A = 25^\circ\text{C}$	TO-252-4	3.125		W
		SOP-8	2		W
	$T_A = 70^\circ\text{C}$	TO-252-4	2		W
		SOP-8	1.28		W
Junction Temperature		T_J	-55 ~ +150		$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150		$^\circ\text{C}$

■ **THERMAL DATA**

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-252-4	θ_{JA}	40	$^\circ\text{C/W}$
	SOP-8		62.5	

Note: Surface Mounted on 1in^2 pad area, $t \leq 10\text{sec}$.

■ **ELECTRICAL CHARACTERISTICS** ($T_J = 25^\circ\text{C}$, unless otherwise specified)

N-CHANNEL

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=10\text{mA}$	40			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=32V, V_{GS}=0V$			1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	1.0		3.0	V
Drain-Source On-State Resistance (Note2)	$R_{DS(ON)}$	$V_{GS}=10V, I_D=6.0A$			31	$\text{m}\Omega$
		$V_{GS}=4.5V, I_D=5.0A$			45	$\text{m}\Omega$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{GS}=0V, V_{DS}=20V, f=1.0\text{MHz}$		400		pF
Output Capacitance	C_{OSS}			54		pF
Reverse Transfer Capacitance	C_{RSS}			45		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge (Note2)	Q_G	$V_{DS}=20V, V_{GS}=10V, I_D=6A$		18		nC
Gate-Source Charge	Q_{GS}			2.8		nC
Gate-Drain Charge	Q_{GD}			3		nC
Turn-ON Delay Time (Note2)	$t_{D(ON)}$	$V_{DS}=20V, V_{GS}=10V, R_G=3\Omega, I_D=1A$		5.2		ns
Turn-ON Rise Time	t_R			16		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			13.6		ns
Turn-OFF Fall Time	t_F			20		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Diode Continuous Forward Current	I_S				3	A
Drain-Source Diode Forward Voltage(Note2)	V_{SD}	$I_S=1A, V_{GS}=0V$		0.77	1	V
Reverse Recovery Time	t_{rr}	$I_{DS}=6A, dI/dt=100A/\mu\text{s}$		20		ns
Reverse Recovery Charge	Q_{rr}			12		nC

■ ELECTRICAL CHARACTERISTICS (Cont.)

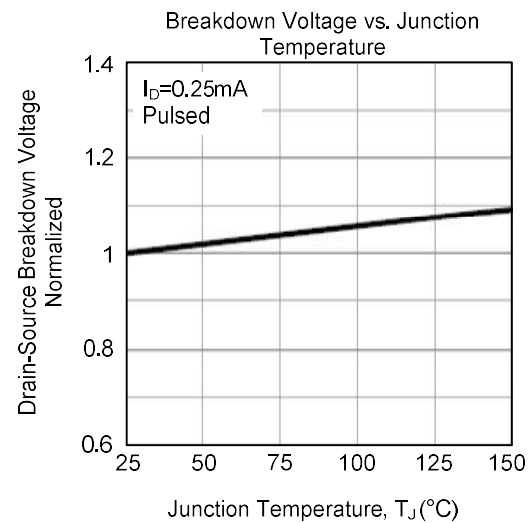
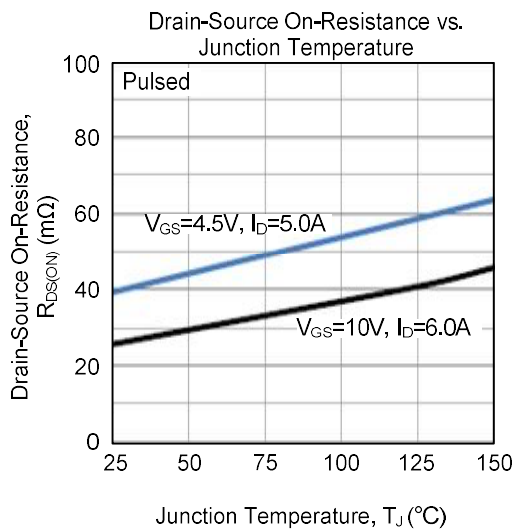
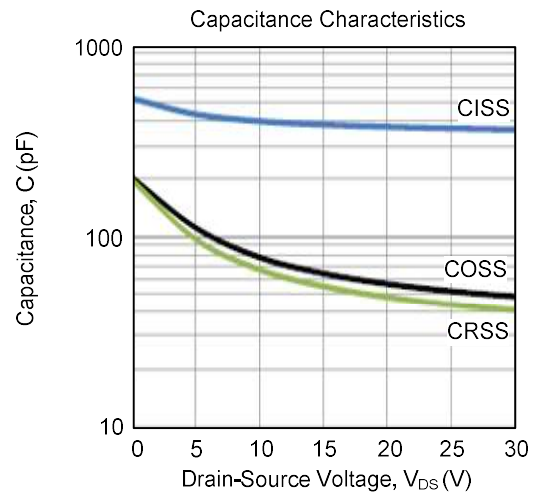
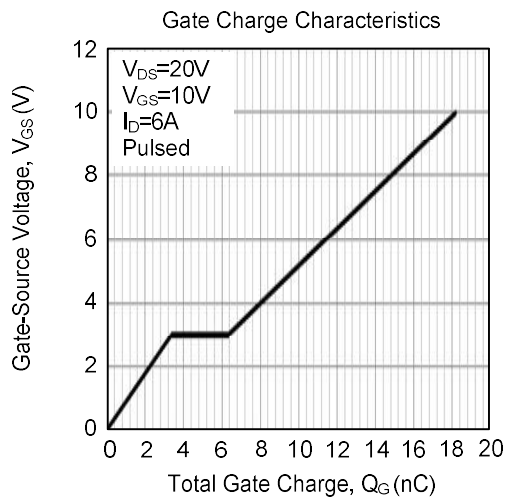
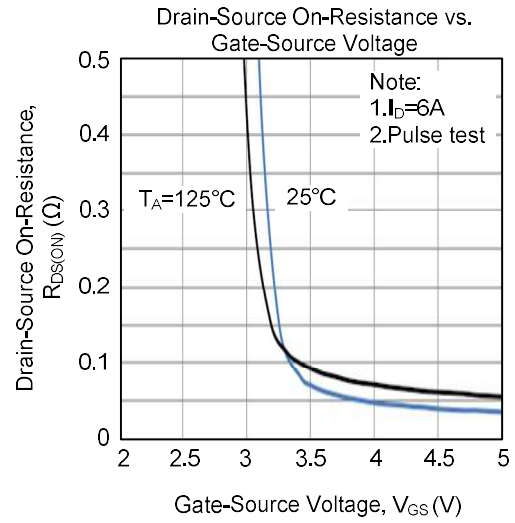
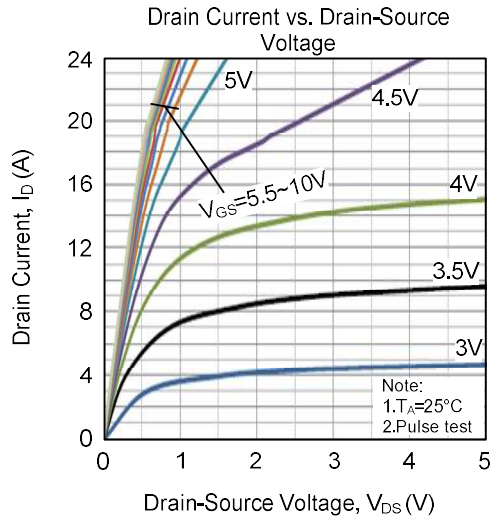
P-CHANNEL

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-10mA$	-40			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=-32V, V_{GS}=0V$			-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0		-3.0	V
Drain-Source On-State Resistance (Note2)	$R_{DS(ON)}$	$V_{GS}=-10V, I_D=-5.0A$			45	$m\Omega$
		$V_{GS}=-4.5V, I_D=-2.0A$			63	$m\Omega$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{GS}=0V, V_{DS}=-20V, f=1.0MHz$		920		pF
Output Capacitance	C_{OSS}			125		pF
Reverse Transfer Capacitance	C_{RSS}			100		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge (Note2)	Q_G	$V_{DS}=-20V, V_{GS}=-10V, I_D=-5A$		22		nC
Gate-Source Charge	Q_{GS}			3.2		nC
Gate-Drain Charge	Q_{GD}			5.5		nC
Turn-ON Delay Time (Note2)	$t_{D(ON)}$	$V_{DS}=-20V, V_{GS}=-10V,$ $R_G=3\Omega, I_D=-1A$		5.2		ns
Turn-ON Rise Time	t_R			17		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			37		ns
Turn-OFF Fall Time	t_F			23		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Drain-Source Diode Forward Voltage(Note2)	V_{SD}	$I_S=-1A, V_{GS}=0V$		-0.75	-1	V
Diode Continuous Forward Current	I_S				-3.2	A
Reverse Recovery Time	t_{rr}	$I_{DS}=-5A, dI/dt=100A/\mu s$		58		ns
Reverse Recovery Charge	Q_{rr}				56	

- Notes: 1. Pulse width limited by $T_{J(MAX)}$
 2. Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 3. Surface Mounted on $1in^2$ pad area, $t \leq 10sec$.

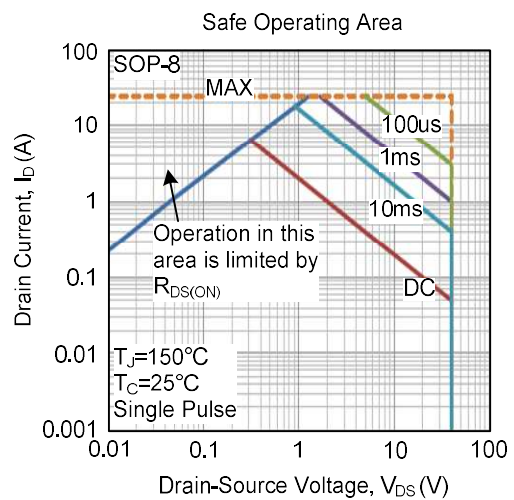
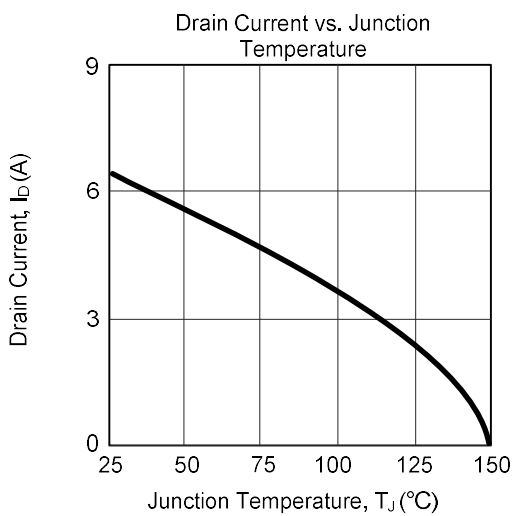
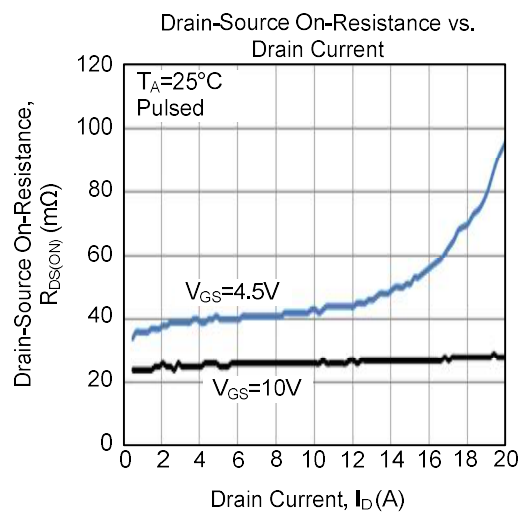
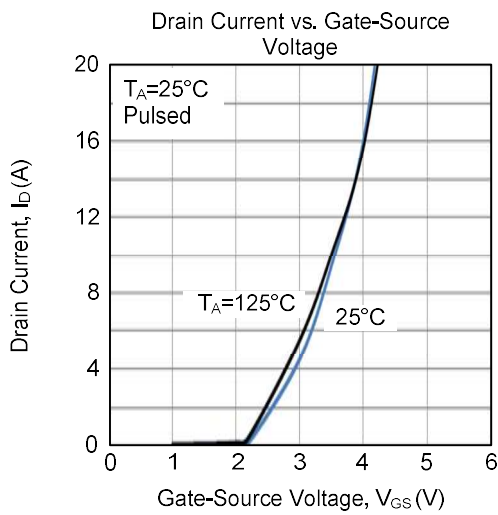
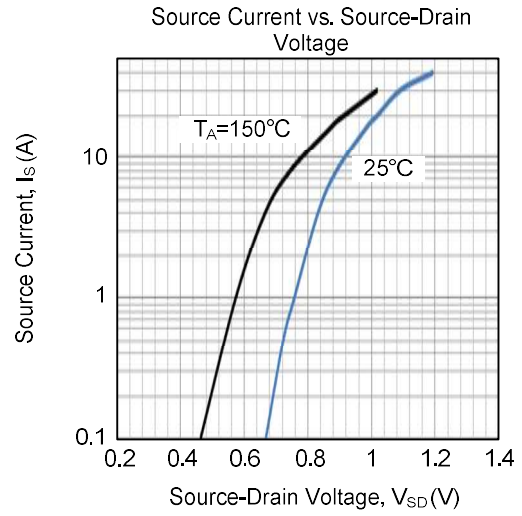
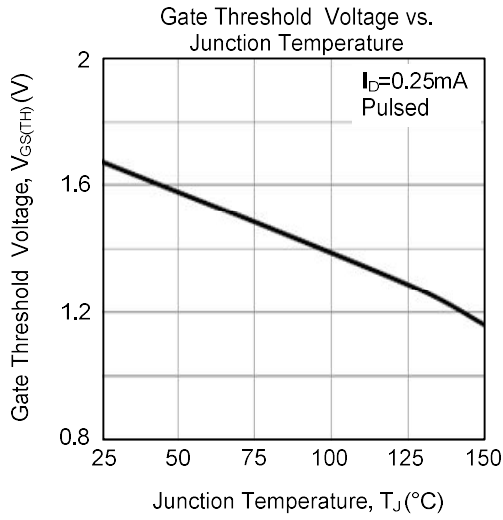
■ TYPICAL CHARACTERISTICS

N-CHANNEL



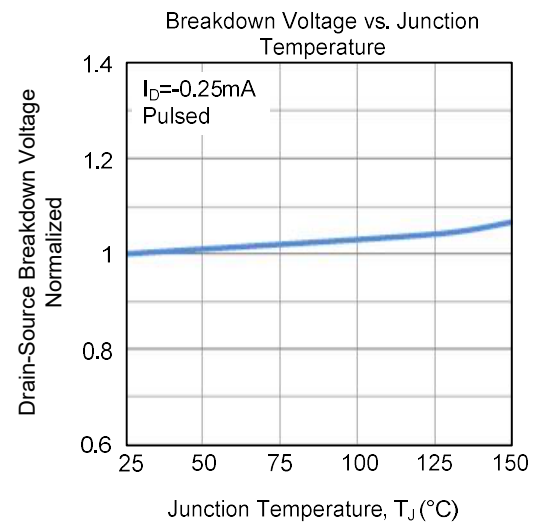
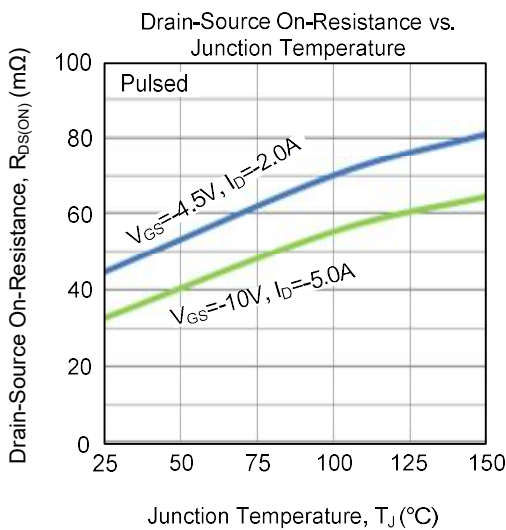
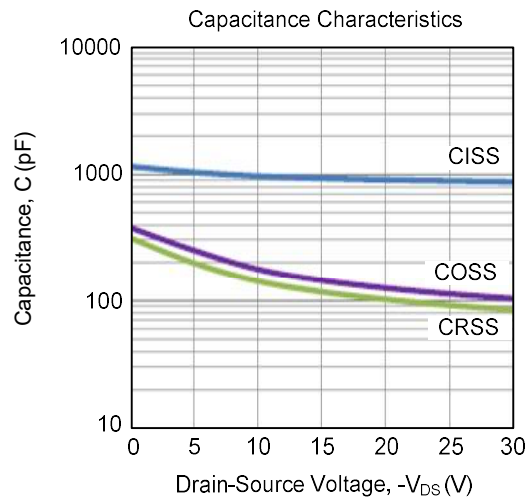
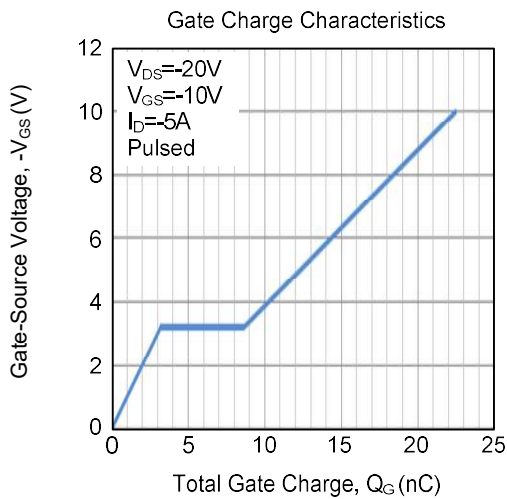
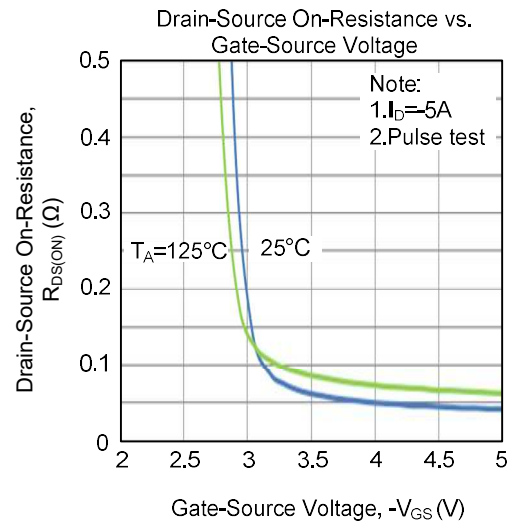
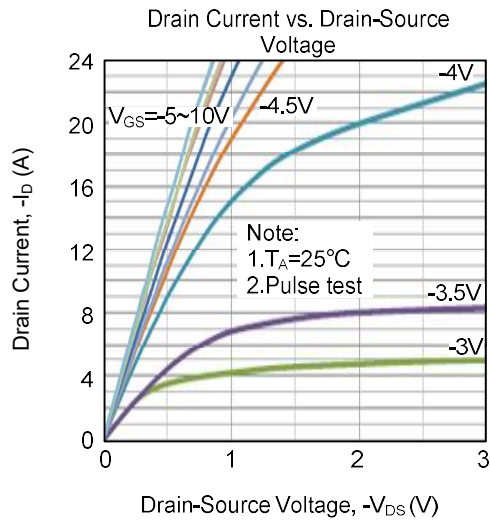
■ TYPICAL CHARACTERISTICS (Cont.)

N-CHANNEL



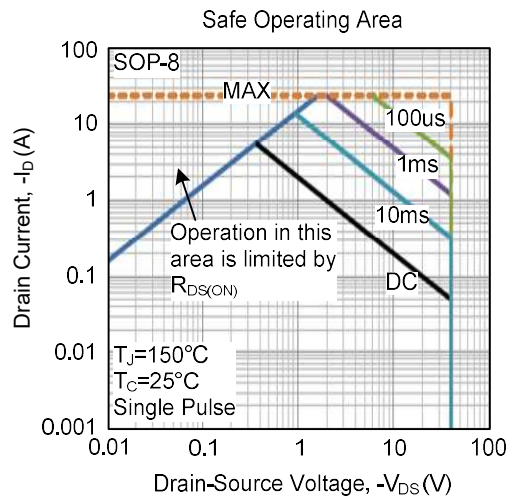
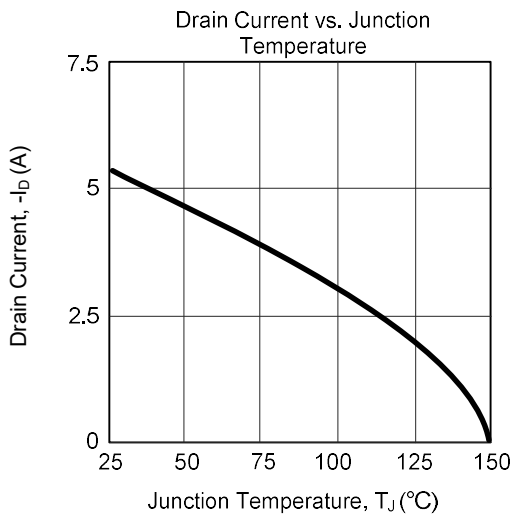
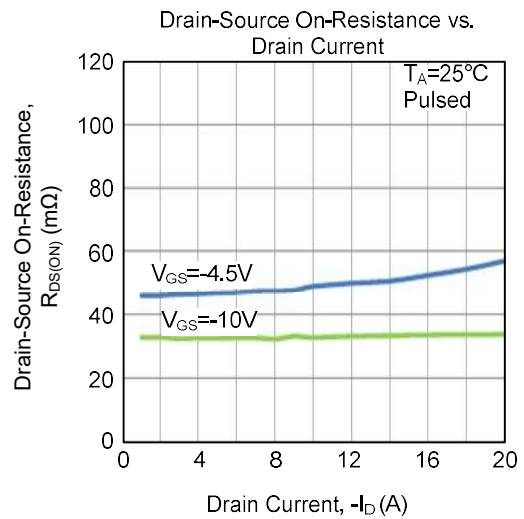
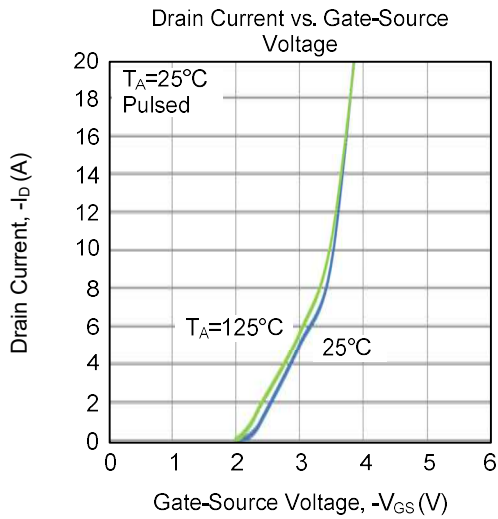
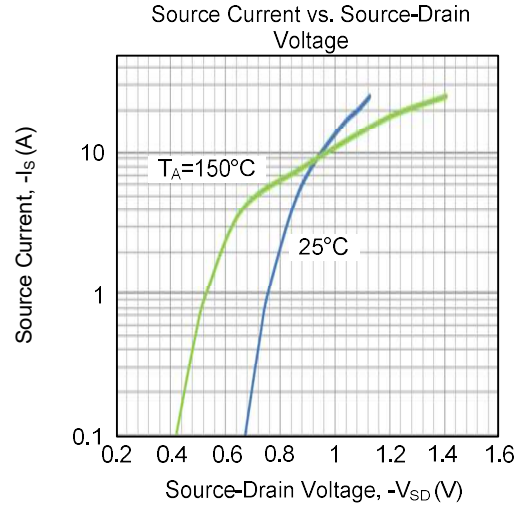
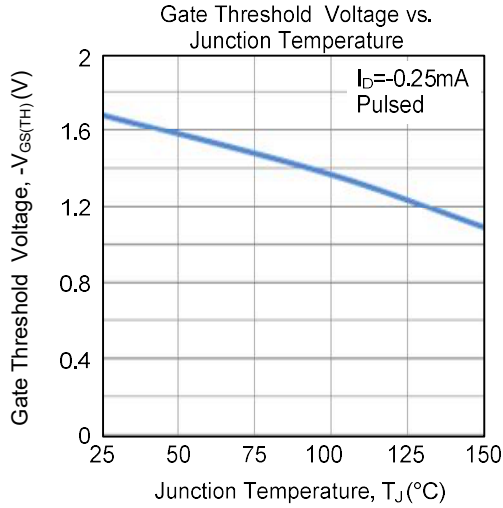
■ TYPICAL CHARACTERISTICS (Cont.)

P-CHANNEL

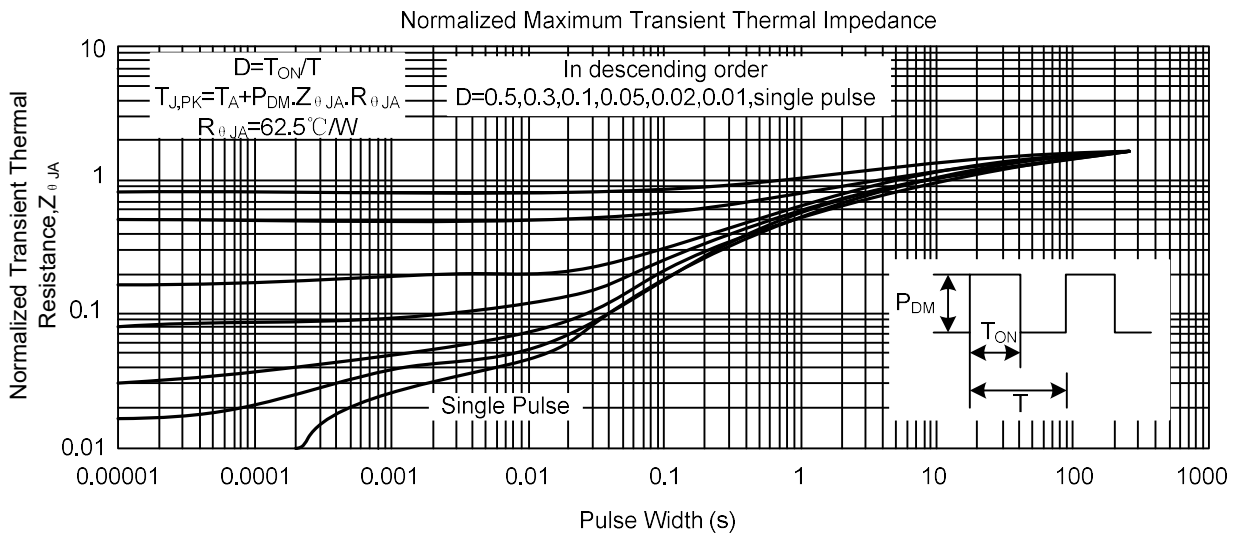
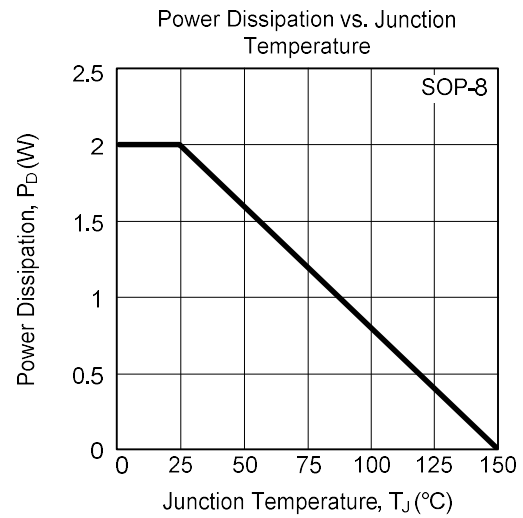
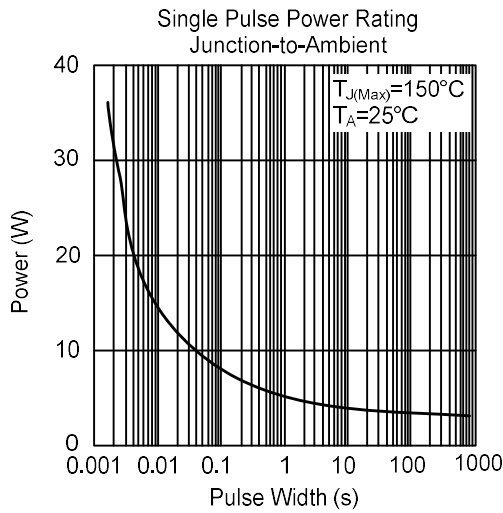


■ TYPICAL CHARACTERISTICS (Cont.)

P-CHANNEL



■ TYPICAL CHARACTERISTICS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.